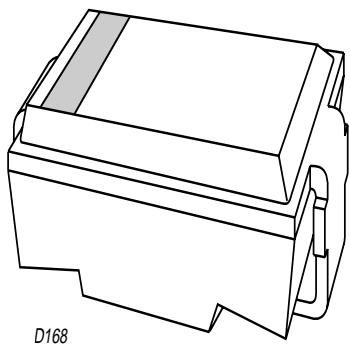


DATA SHEET



BYG85B Fast soft-recovery rectifier

Product specification

1998 Nov 25

Fast soft-recovery rectifier**BYG85B****FEATURES**

- Glass passivated
- High maximum operating temperature
- Low leakage current
- Excellent stability
- UL 94V-O classified plastic package
- Shipped in 12 mm embossed tape.

DESCRIPTION

DO-214AC surface mountable package with glass passivated chip.

The well-defined void-free case is of a transfer-moulded thermo-setting plastic.

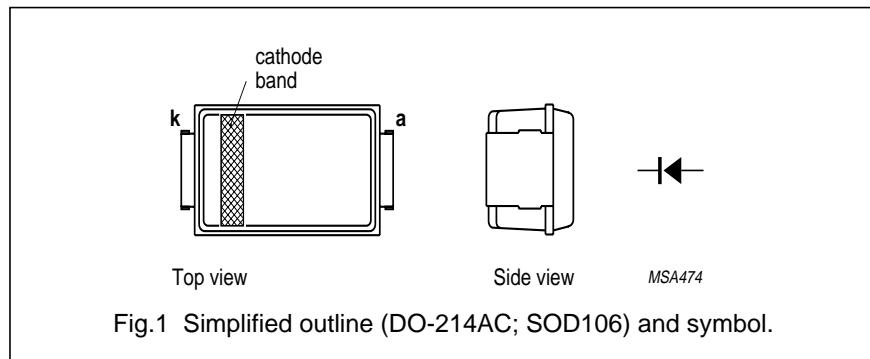


Fig.1 Simplified outline (DO-214AC; SOD106) and symbol.

LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V_{RRM}	repetitive peak reverse voltage		–	100	V
V_R	continuous reverse voltage		–	100	V
$I_{F(AV)}$	average forward current	$T_{tp} = 100 \text{ }^\circ\text{C}$; averaged over any 20 ms period; see Figs 2 and 7	–	2.5	A
$I_{F(AV)}$	average forward current	$T_{amb} = 60 \text{ }^\circ\text{C}$; Al_2O_3 PCB mounting (see Fig.11); averaged over any 20 ms period; see Fig.3	–	1.3	A
$I_{F(AV)}$	average forward current	$T_{amb} = 60 \text{ }^\circ\text{C}$; epoxy PCB mounting (see Fig.11); averaged over any 20 ms period; see Fig.3	–	0.98	A
I_{FRM}	repetitive peak forward current	$T_{tp} = 100 \text{ }^\circ\text{C}$; see Fig.3	–	23	A
I_{FRM}	repetitive peak forward current	$T_{amb} = 60 \text{ }^\circ\text{C}$; Al_2O_3 PCB mounting; see Fig.5	–	12	A
I_{FRM}	repetitive peak forward current	$T_{amb} = 60 \text{ }^\circ\text{C}$; epoxy PCB mounting; see Fig.6	–	8.5	A
I_{FSM}	non-repetitive peak forward current	$t = 10 \text{ ms}$ half sine wave; $T_j = T_{j\max}$ prior to surge; $V_R = V_{RRM\max}$	–	35	A
T_{stg}	storage temperature		-65	+175	$^\circ\text{C}$
T_j	junction temperature		-65	+175	$^\circ\text{C}$

Fast soft-recovery rectifier

BYG85B

ELECTRICAL CHARACTERISTICS $T_j = 25^\circ\text{C}$ unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
V_F	forward voltage	$I_F = 2 \text{ A}; T_j = T_{j\max};$ see Fig.8	—	—	0.78	V
		$I_F = 2 \text{ A};$ see Fig.8	—	—	0.98	V
$V_{(BR)R}$	reverse avalanche breakdown voltage	$I_R = 0.1 \text{ mA}$	120	—	—	V
I_R	reverse current	$V_R = V_{RRM\max};$ see Fig.9	—	—	5	μA
		$V_R = V_{RRM\max}; T_j = 165^\circ\text{C};$ see Fig.9	—	—	150	μA
t_{rr}	reverse recovery time	when switched from $I_F = 0.5 \text{ A}$ to $I_R = 1 \text{ A};$ measured at $I_R = 0.25 \text{ A};$ see Fig.13	—	—	12.5	ns
C_d	diode capacitance	$f = 1 \text{ MHz}; V_R = 0;$ see Fig.10	—	110	—	pF
$ dI_R /dt$	maximum slope of reverse recovery current	when switched from $I_F = 1 \text{ A}$ to $V_R \geq 30 \text{ V}$ and $dI_F/dt = -1 \text{ A}/\mu\text{s};$ see Fig.12	—	—	2	A/ μs

THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT
$R_{th j\text{-tp}}$	thermal resistance from junction to tie-point		25	K/W
$R_{th j\text{-a}}$	thermal resistance from junction to ambient	note 1	100	K/W
		note 2	150	K/W

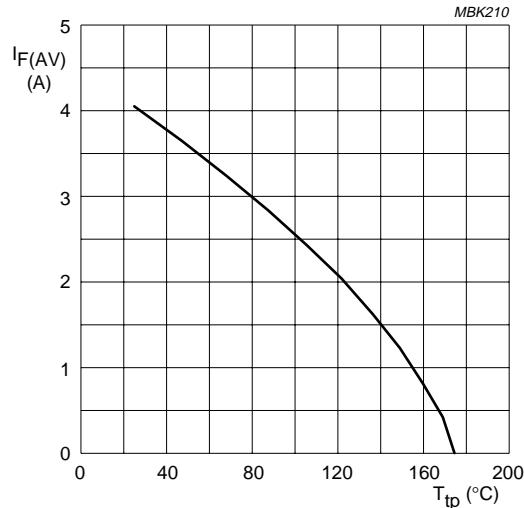
Notes

1. Device mounted on Al_2O_3 printed-circuit board, 0.7 mm thick; thickness of copper $\geq 35 \mu\text{m},$ see Fig.11.
2. Device mounted on epoxy-glass printed-circuit board, 1.5 mm thick; thickness of copper $\geq 40 \mu\text{m},$ see Fig.11.
For more information please refer to the '*General Part of associated Handbook*'.

Fast soft-recovery rectifier

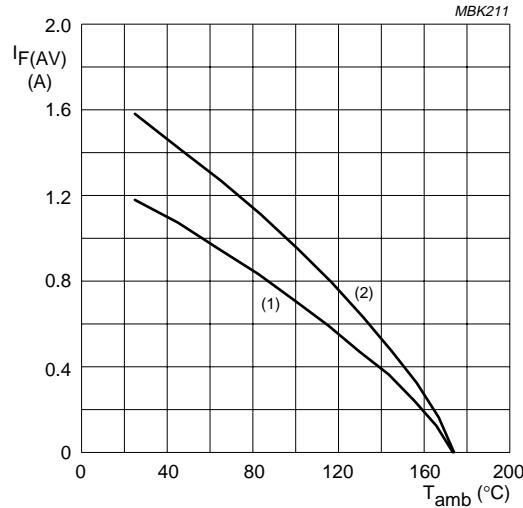
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GRAPHICAL DATA



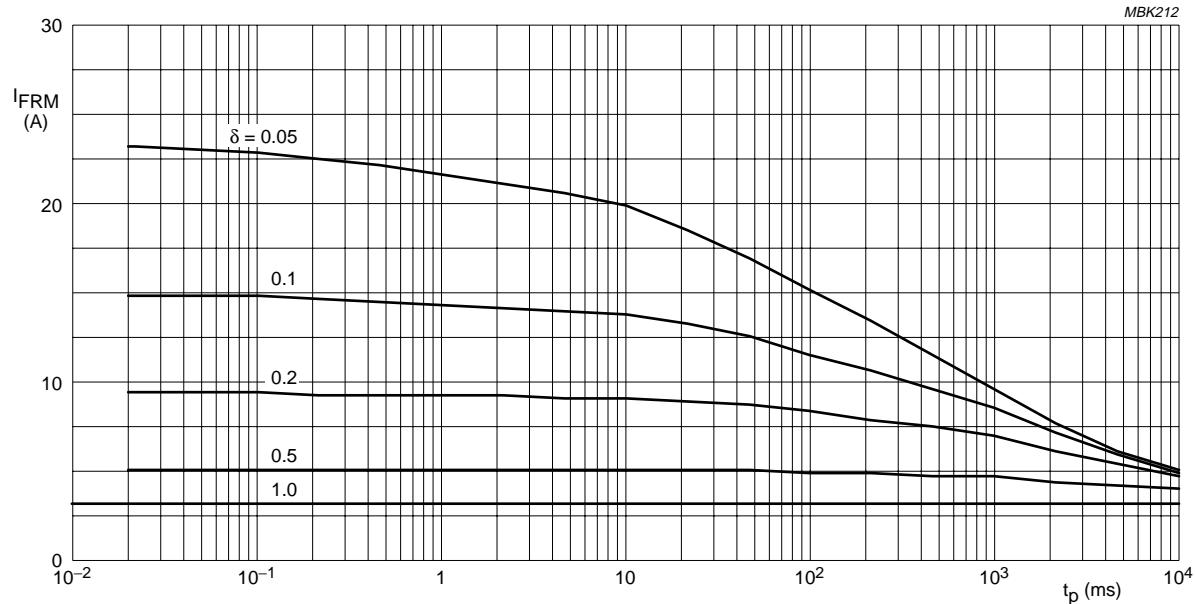
$a = 1.42$; $V_R = V_{RRMmax}$; $\delta = 0.5$.
Switched mode application.

Fig.2 Maximum permissible average forward current as a function of tie-point temperature (including losses due to reverse leakage).



$a = 1.42$; $V_R = V_{RRMmax}$; $\delta = 0.5$; Switched mode application;
Device mounted as shown in Fig.11.
1: epoxy PCB 2: Al₂O₃ PCB.

Fig.3 Maximum permissible average forward current as a function of ambient temperature (including losses due to reverse leakage).



$T_{tp} = 100$ °C; $R_{th\ j\cdot tp} = 25$ K/W.
 V_{RRMmax} during 1 - δ ; curves include derating for $T_{j\ max}$ at $V_{RRM} = 100$ V.

Fig.4 Maximum repetitive peak forward current as a function of pulse time (square pulse) and duty factor.

Fast soft-recovery rectifier

BYG85B

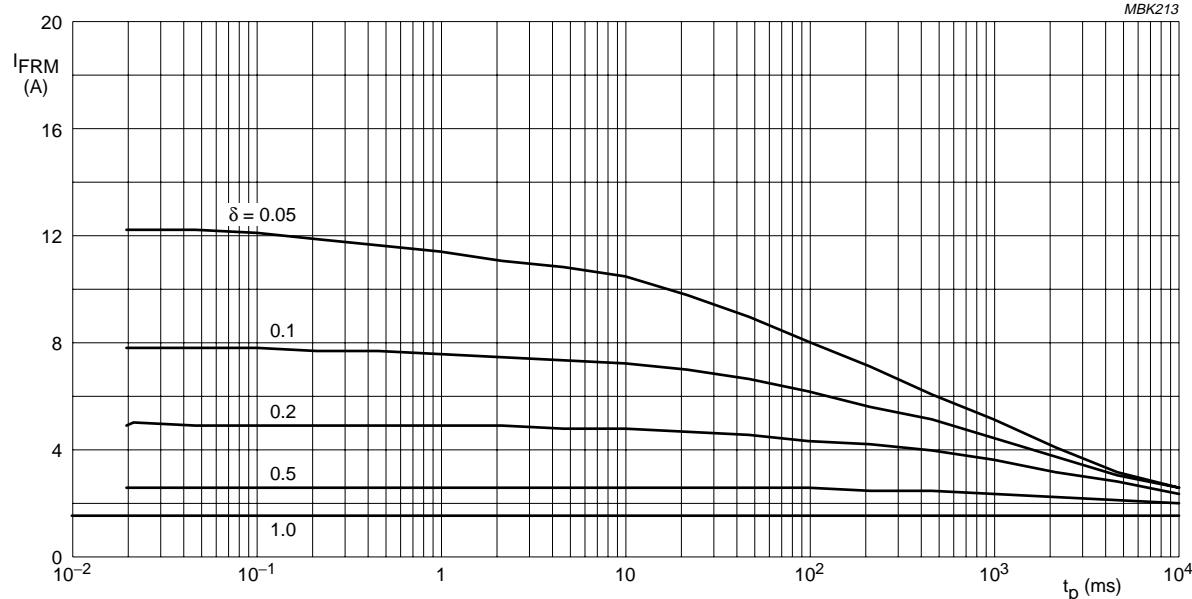
 $T_{amb} = 60^\circ\text{C}; R_{th\ j-a} = 100 \text{ K/W.}$ V_{RRMmax} during $1 - \delta$; curves include derating for $T_{j\ max}$ at $V_{RRM} = 100 \text{ V.}$

Fig.5 Maximum repetitive peak forward current as a function of pulse time (square pulse) and duty factor.

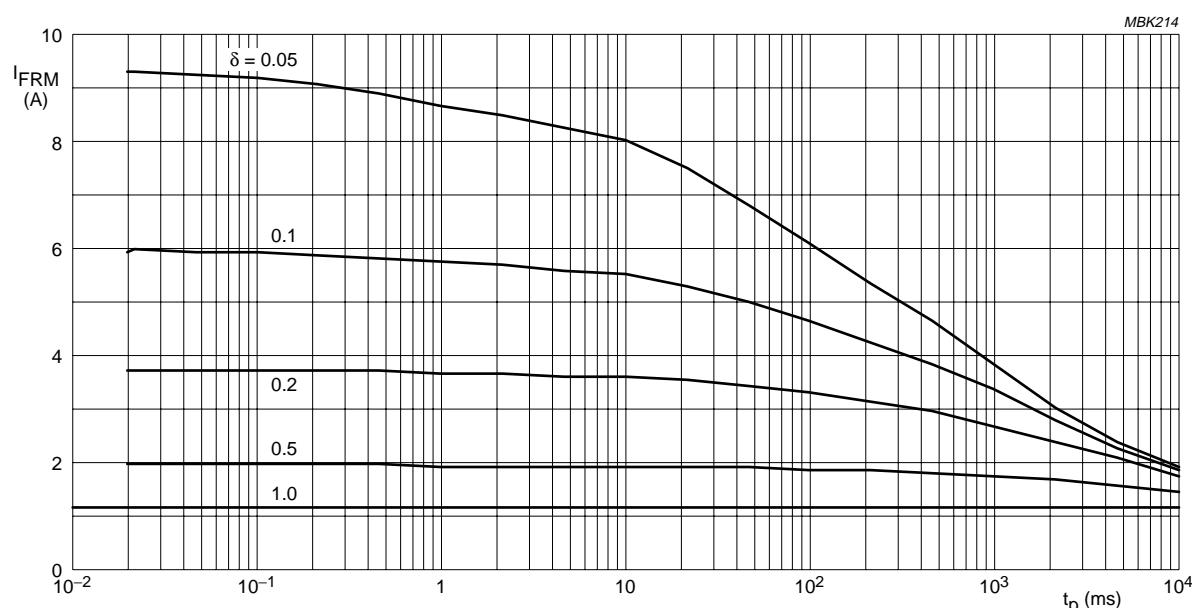
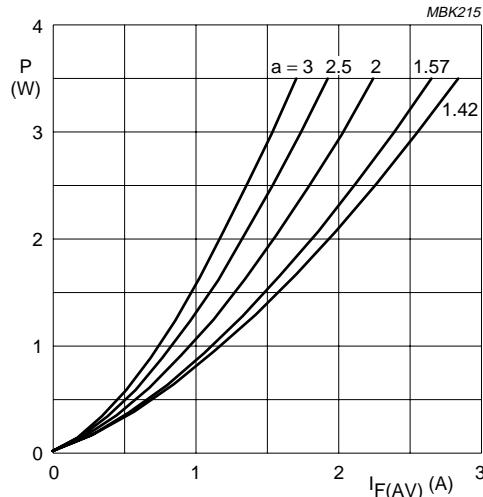
 $T_{amb} = 60^\circ\text{C}; R_{th\ j-a} = 150 \text{ K/W.}$ V_{RRMmax} during $1 - \delta$; curves include derating for $T_{j\ max}$ at $V_{RRM} = 100 \text{ V.}$

Fig.6 Maximum repetitive peak forward current as a function of pulse time (square pulse) and duty factor.

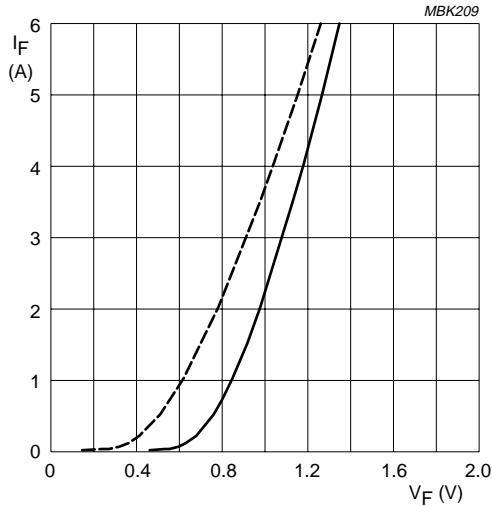
Fast soft-recovery rectifier

BYG85B



$$a = I_{F(RMS)} / I_{F(AV)}; V_R = V_{RRMmax}; \delta = 0.5.$$

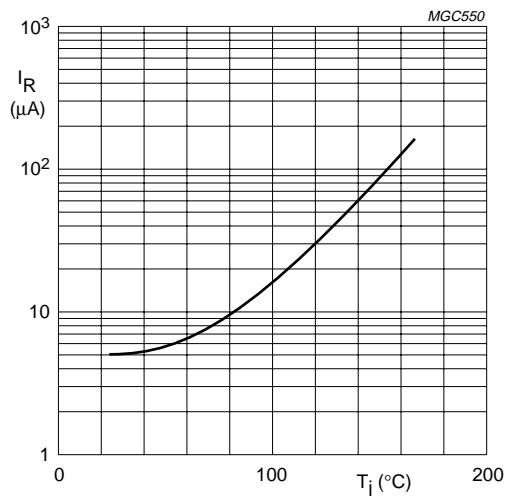
Fig.7 Maximum steady state power dissipation (forward plus leakage current losses, excluding switching losses) as a function of average forward current.



Dotted line: $T_j = 175^\circ\text{C}$.

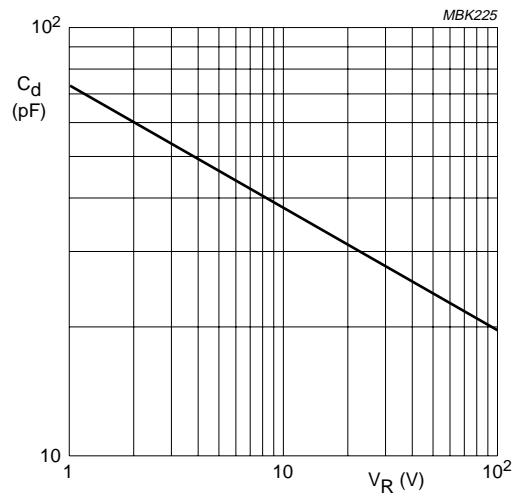
Solid line: $T_j = 25^\circ\text{C}$.

Fig.8 Forward current as a function of forward voltage; maximum values.



$$V_R = V_{RRMmax}.$$

Fig.9 Reverse current as a function of junction temperature; maximum values.



$$f = 1 \text{ MHz}; T_j = 25^\circ\text{C}.$$

Fig.10 Diode capacitance as a function of reverse voltage; typical values.

Fast soft-recovery rectifier

BYG85B

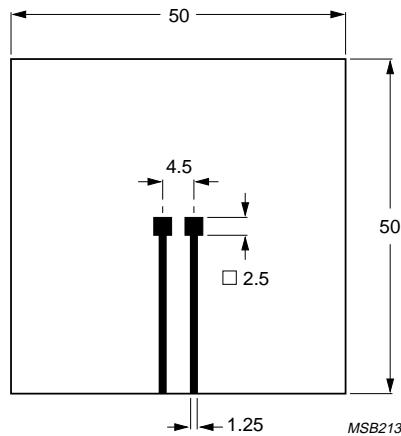


Fig.11 Printed-circuit board for surface mounting.

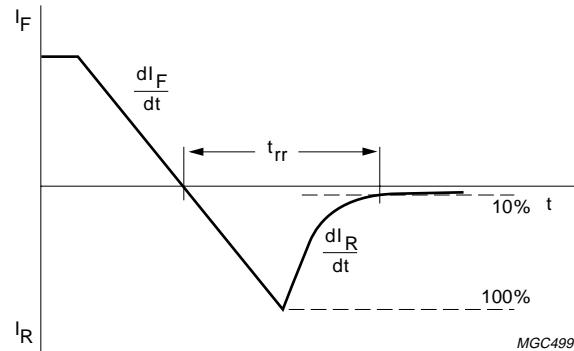
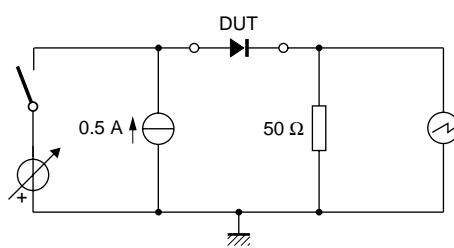


Fig.12 Reverse recovery definitions.



Rise time oscilloscope: $t_r \leq 2$ ns.
Turn-on time switch: $t \leq 3$ ns.

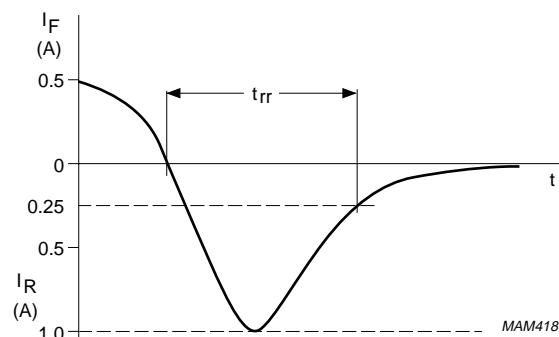


Fig.13 Test circuit and reverse recovery time waveform and definition.

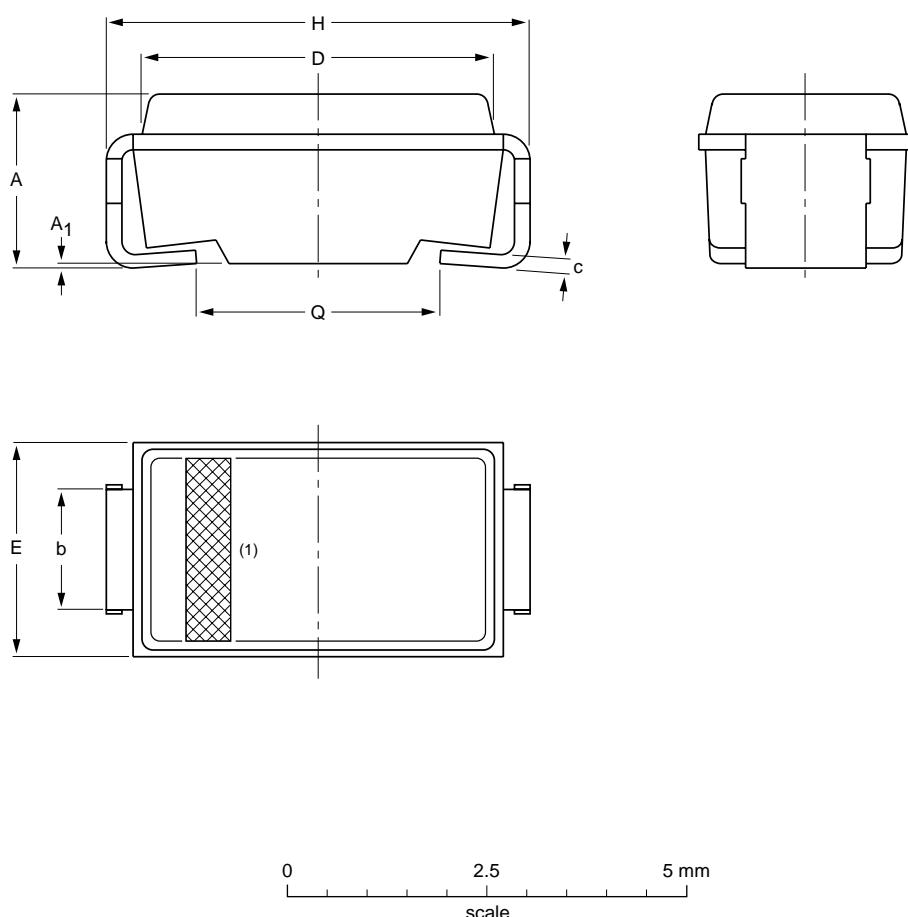
Fast soft-recovery rectifier

BYG85B

PACKAGE OUTLINE

Transfer-moulded thermo-setting plastic small rectangular surface mounted package;
2 connectors

SOD106



DIMENSIONS (mm are the original dimensions)

UNIT	A	A ₁	b	c	D	E	H	Q
mm	2.3 2.0	0.05	1.6 1.4	0.2	4.5 4.3	2.8 2.4	5.5 5.1	3.3 2.7

Note

1. The marking band indicates the cathode.

OUTLINE VERSION	REFERENCES				EUROPEAN PROJECTION	ISSUE DATE
	IEC	JEDEC	EIAJ			
SOD106		DO-214AC				97-06-09

Fast soft-recovery rectifier

BYG85B

DEFINITIONS

Data sheet status	
Objective specification	This data sheet contains target or goal specifications for product development.
Preliminary specification	This data sheet contains preliminary data; supplementary data may be published later.
Product specification	This data sheet contains final product specifications.
Limiting values	
Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification is not implied. Exposure to limiting values for extended periods may affect device reliability.	
Application information	
Where application information is given, it is advisory and does not form part of the specification.	

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NOTES

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